

# NPN General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.0 A. Sourced from Process 39.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |  |
|-----------------------------------|--|-------------|-------|--|
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | 80          | V     |  |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 80          | V     |  |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5.0         | V     |  |
| Ic                                | Collector Current - Continuous                   | 1.2         | А     |  |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |  |

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## Thermal Characteristics TA = 25°C unless otherwise noted

| Symbol              | Characteristic                          | Max Un  |          | Units |
|---------------------|---|---------|----------|-------|
|                     |   | TN6717A | *NZT6717 |       |
| PD                  | Total Device Dissipation                | 1.0     | 1.0      | W     |
|                     | Derate above 25°C                       | 8.0     | 8.0      | mW/°C |
| R <sub>θJC</sub>    | Thermal Resistance, Junction to Case    | 50      |          | °C/W  |
| $R_{	ext{	hetaJA}}$ | Thermal Resistance, Junction to Ambient | 125     | 125      | °C/W  |

\*Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

## **NPN General Purpose Amplifier** (c

| continued) |  |
|------------|--|

| Symbol               | Parameter                               | Test Conditions                            | Min | Max | Units |
|----------------------|---|--|-----|-----|-------|
| OFF CHAF             | RACTERISTICS                            |  |     |     |       |
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown<br>Voltage* | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$ | 80  |     | V     |
| V <sub>(BR)CBO</sub> | Collector-Base Breakdown Voltage        | $I_{C} = 100 \ \mu A, \ I_{E} = 0$         | 80  |     | V     |
| V <sub>(BR)EBO</sub> | Emitter-Base Breakdown Voltage          | $I_E = 100 \ \mu A, I_C = 0$               | 5.0 |     | V     |
| I <sub>CBO</sub>     | Collector-Cutoff Current                | $V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$ |     | 0.1 | μA    |
| I <sub>EBO</sub>     | Emitter-Cutoff Current                  | $V_{EB} = 5.0 \text{ V}, I_C = 0$          |     | 0.1 | μA    |

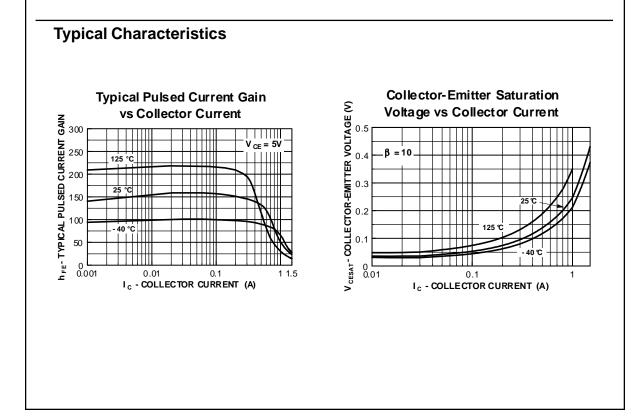
HARACTERISTICS

| h <sub>FE</sub>      | DC Current Gain                      | $    I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V} \\     I_C = 250 \text{ mA}, V_{CE} = 1.0 \text{ V} \\     I_C = 500 \text{ mA}, V_{CE} = 1.0 \text{ V} $ | 80<br>50<br>20 | 250  |   |
|----------------------|--------------------------------------|--|----------------|------|---|
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | $I_{\rm C} = 250 \text{ mA}, I_{\rm B} = 10 \text{ mA}$  |                | 0.35 | V |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage              | $I_{C} = 250 \text{ mA}, V_{CE} = 1.0 \text{ V}$   |                | 1.2  | V |

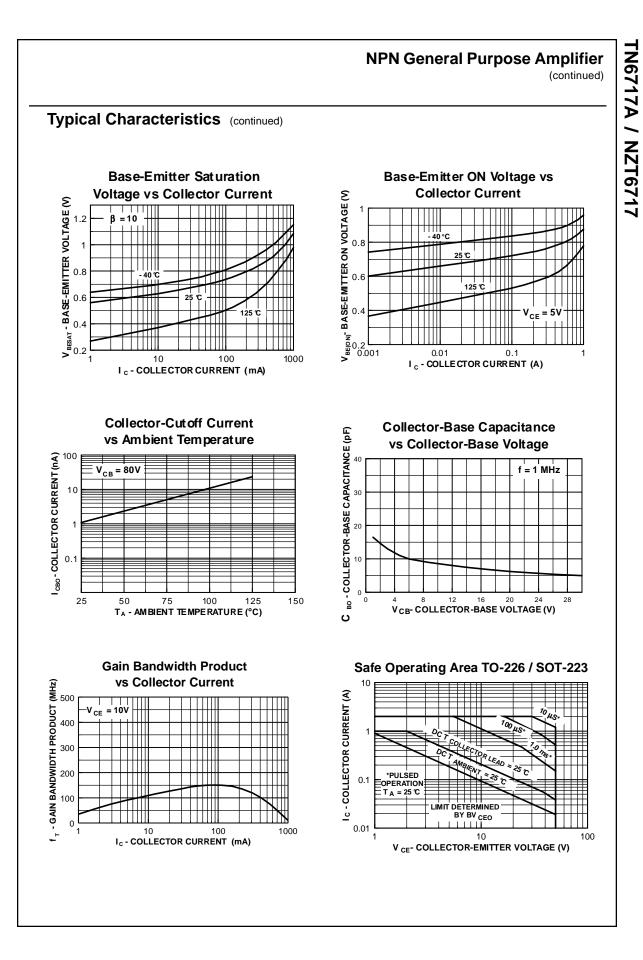
## SMALL SIGNAL CHARACTERISTICS

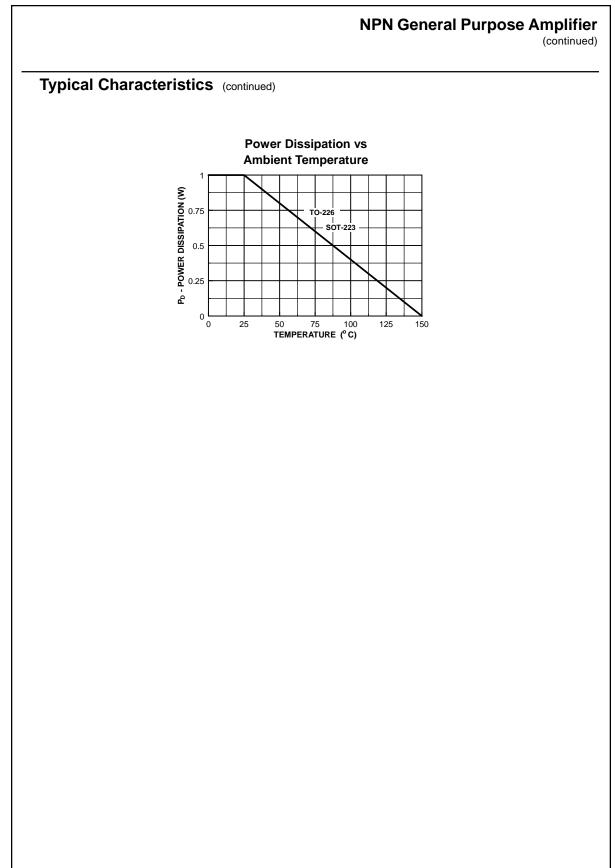
| h <sub>fe</sub> | Small-Signal Current Gain  | $I_{c}$ = 200 mA, $V_{ce}$ = 5.0 V,<br>f = 20 MHz                       | 2.5 | 25 |    |
|-----------------|----------------------------|---|-----|----|----|
| C <sub>cb</sub> | Collector-Base Capacitance | $V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1.0 \text{ MHz}$ |     | 30 | pF |

\*Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  1.0%

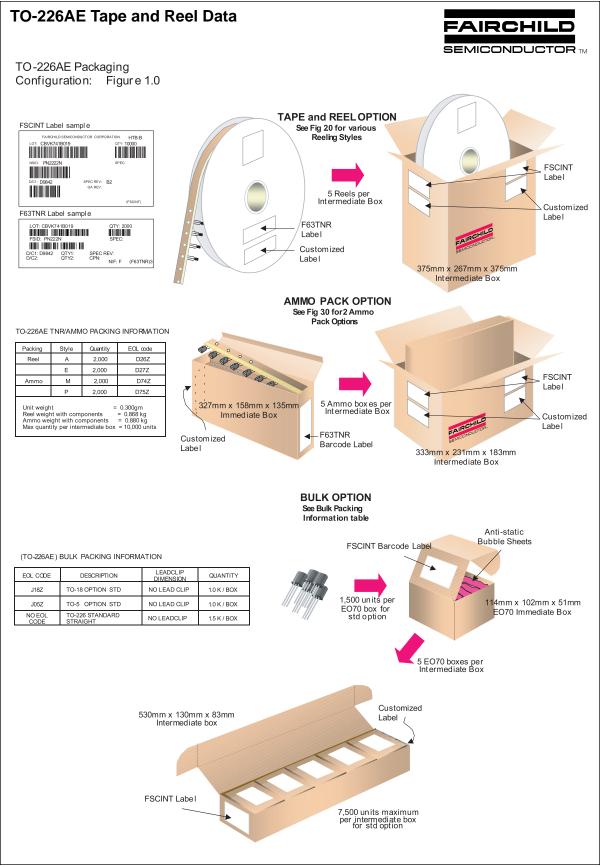


TN6717A / NZT6717



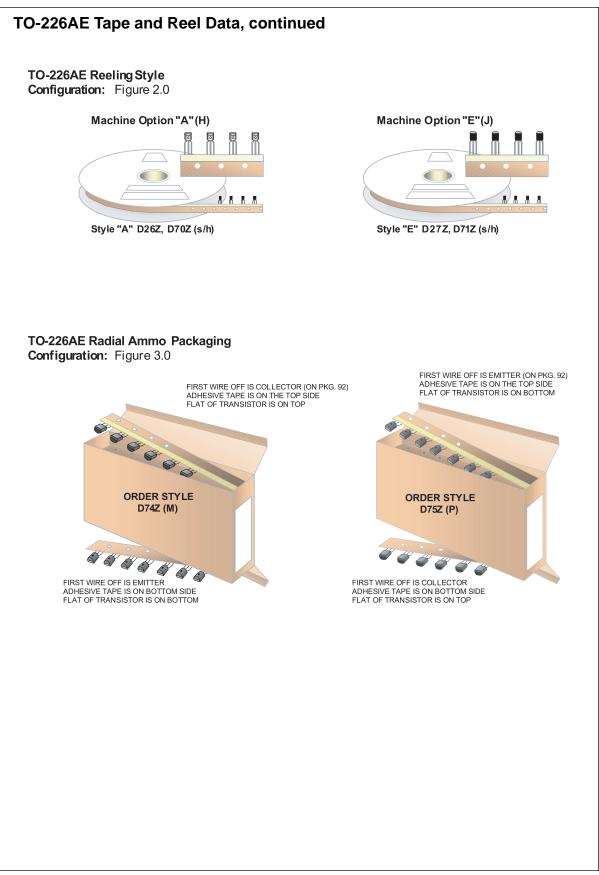


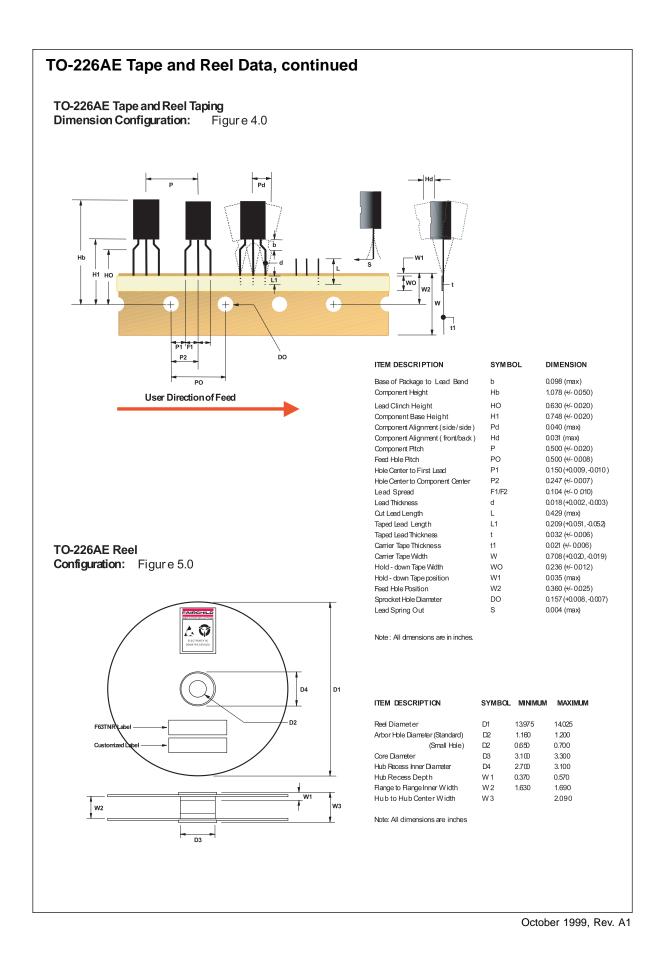
TN6717A / NZT6717

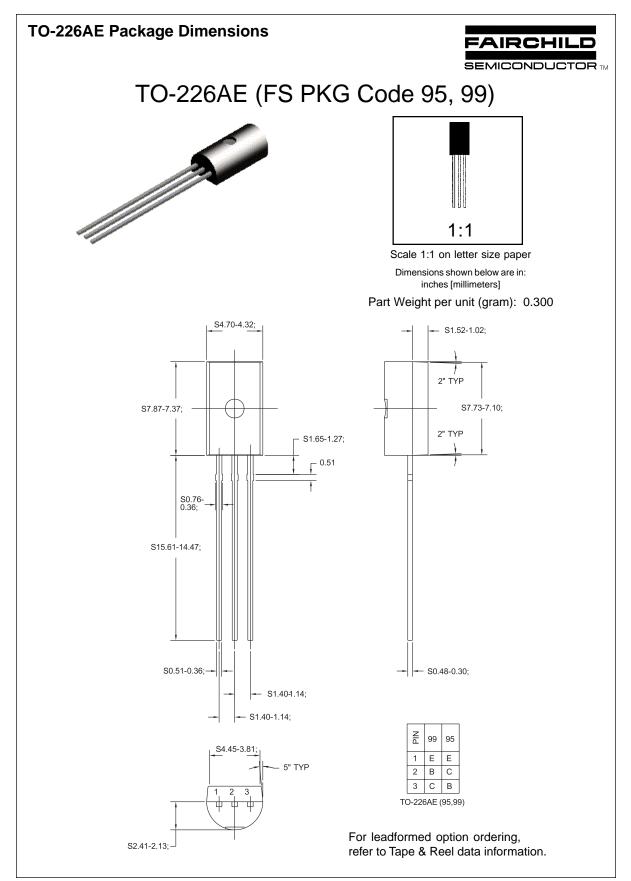


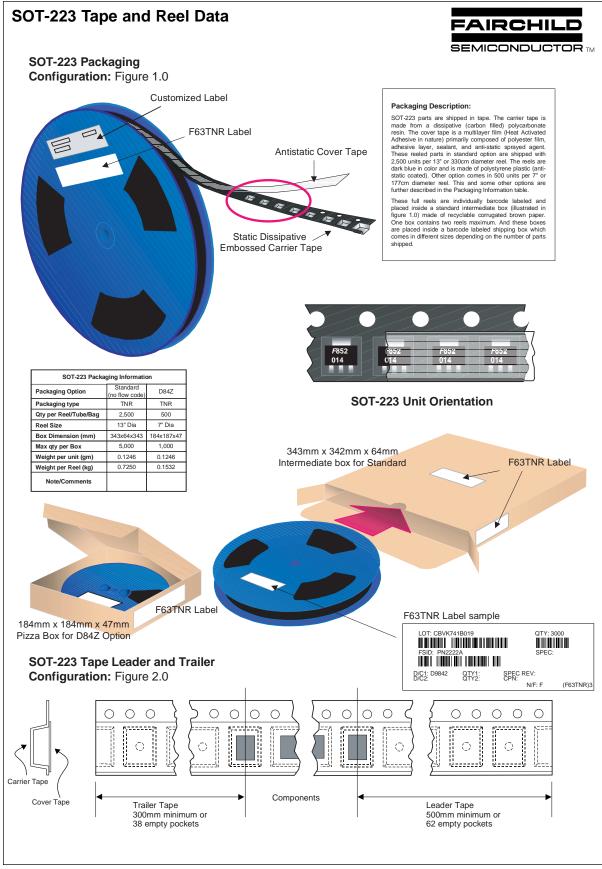
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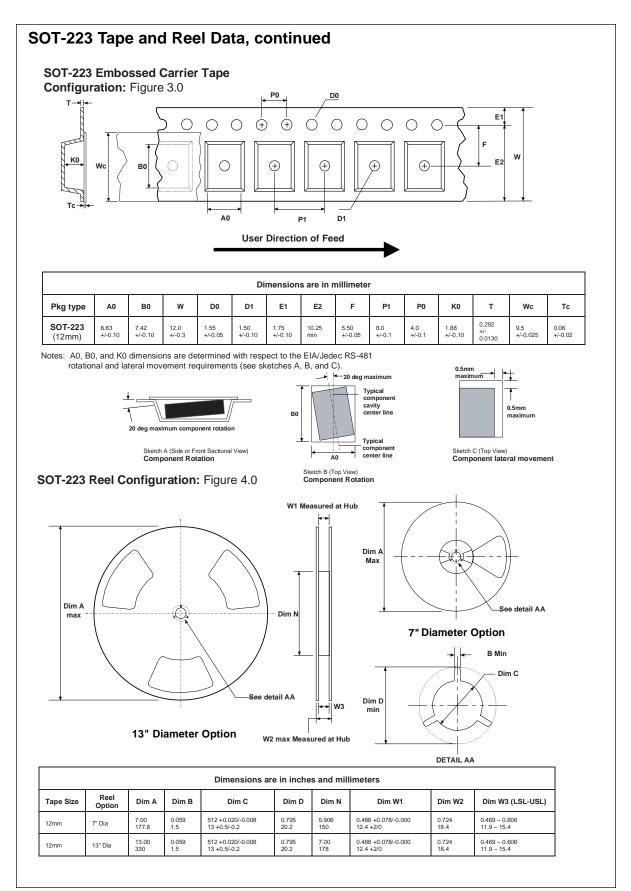


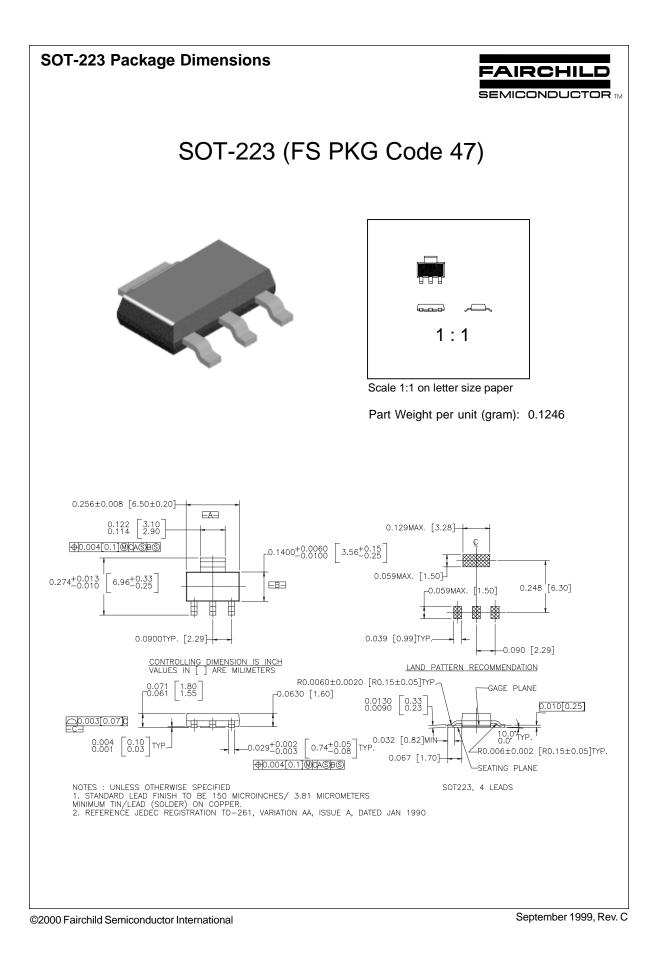




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